Diode Semiconductor Device - Page 1 of 1



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Me	stal
Οv	rerall Length:
0.3	360 inches
Те	rminal Length:
1.2	250 inches
Ov	erall Diameter:
0.2	220 inches
Мо	ounting Method:
Те	rminal
Fe	atures Provided:
He	rmetically sealed case
Se	miconductor Material:
Sili	icon
Ро	wer Rating Per Characteristic:
200	0.0 milliwatts total power dissipation
Ма	iximum Operating Tempurature Per Measurement Point:
200	0.0 degrees celsius ambient air
Те	rminal Type And Quantity:
2 u	ininsulated wire lead
Sh	elf Life:
N/a	a
Un	it Of Measure:
De	militarization:
No	
Fii	g:
A1	10a0